TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

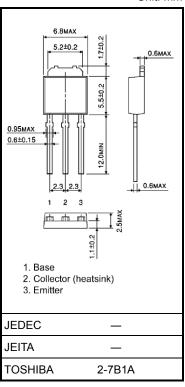
# 2SC3303

#### High Current Switching Applications DC-DC Converter Applications

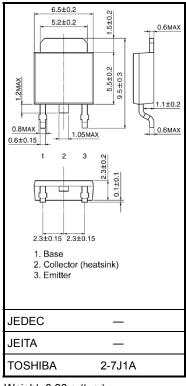
- Low collector saturation voltage: VCE (sat) = 0.4 V (max) (IC = 3 A)
- High speed switching time:  $t_{stg} = 1.0 \ \mu s$  (typ.)

#### Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	100	V	
Collector-emitter voltage		V <sub>CEO</sub>	80	V	
Emitter-base voltage		V <sub>EBO</sub>	7	V	
Collector current	DC	Ι <sub>C</sub>	5	A	
	Pulse	I <sub>CP</sub>	8		
Base current		Ι <sub>Β</sub>	1	А	
Collector power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	ГС	20		
Junction temperature		Тј	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Weight: 0.36 g (typ.)



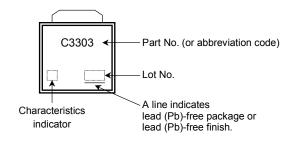
Weight: 0.36 g (typ.)

## Electrical Characteristics (Ta = 25°C)

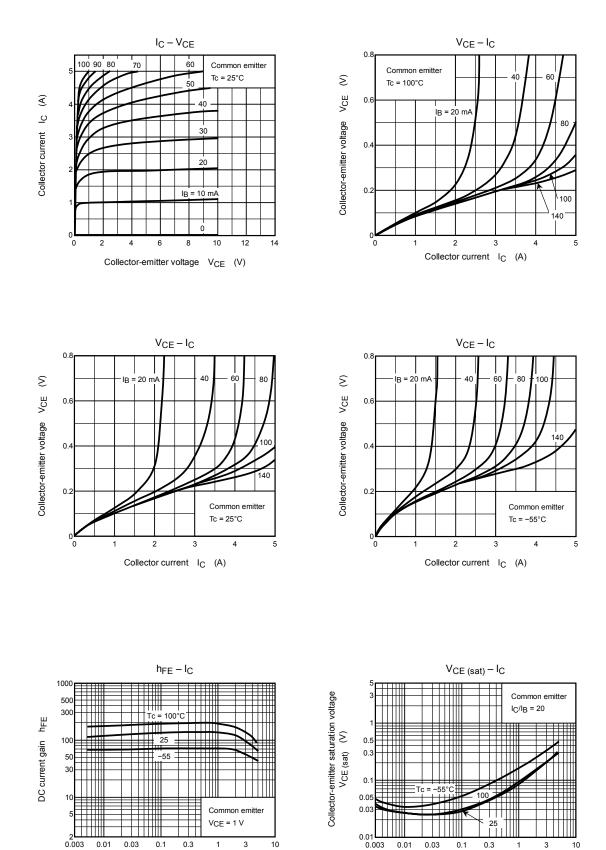
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off c	urrent	I <sub>CBO</sub>	V <sub>CB</sub> = 100 V, I <sub>E</sub> = 0	_	_	1	μA
Emitter cut-off cu	rrent	I <sub>EBO</sub>	V <sub>EB</sub> = 7 V, I <sub>C</sub> = 0	_	—	1	μA
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	80	_	_	V
DC current gain		h <sub>FE (1)</sub> (Note)	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 1 A	70	_	240	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 3 A	40	_	—	
Collector-emitter	saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 3 A, I <sub>B</sub> = 0.15 A	_	0.2	0.4	V
Base-emitter satu	ration voltage	V <sub>BE (sat)</sub>	I <sub>C</sub> = 3 A, I <sub>B</sub> = 0.15 A	_	0.9	1.2	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = 4 V, I <sub>C</sub> = 1 A	_	120	_	MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	80	_	pF
Switching time	Turn-on time	t <sub>on</sub>	20 µs I <sub>B1</sub> INPUTo IB2 V <sub>CC</sub> ≈ 30 V	_	0.2	_	
	Storage time	t <sub>stg</sub>		_	1.0	_	μs
	Fall time	t <sub>f</sub>	I <sub>B1</sub> = −I <sub>B2</sub> = 0.15 A, DUTY CYCLE ≤ 1%	_	0.1	_	

Note: hFE (1) classification O: 70 to 140, Y: 120 to 240

### Marking



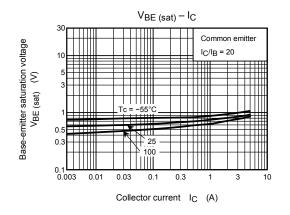
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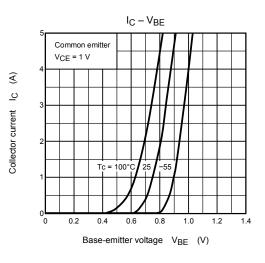


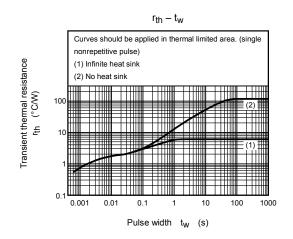
Collector current I<sub>C</sub> (A)

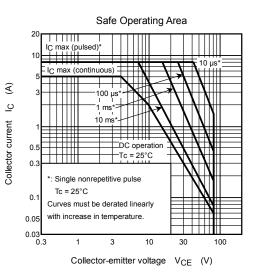
Collector current  $I_C$  (A)

# TOSHIBA









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